TOSHIBA Transistor Silicon-Germanium NPN Epitaxial Planar Type

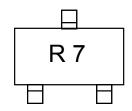
# MT3S113

VHF-UHF Band Low-Noise, Low-Distortion Amplifier Applications

#### **FEATURES**

- Low Noise Figure:NF=1.15dB (typ.) (@ f=1GHz)
- High Gain:|S21e|<sup>2</sup>=11.8dB (typ.) (@ f=1GHz)

### Marking



## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-emitter voltage	V <sub>CES</sub>	13	V
Collector-emitter voltage	V <sub>CEO</sub>	5.3	V
Emitter-base voltage	V <sub>EBO</sub>	0.6	V
Collector-current	IC	100	mA
Base-current	ΙΒ	10	mA
Collector power dissipation	P <sub>C</sub> (Note1)	800	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

1. Base
2. Emitter
3. Collector
S-Mini
JEDEC TO-236
JEITA SC-59
TOSHIBA 2-3F1A

Weight: 0.012 g (typ.)

Note1:The device is mounted on a ceramic board (25.4 mm x 25.4 mm x 0.8 mm (t))

Note2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA	10.5	12.5	_	GHz
Insertion gain	S21e  <sup>2</sup> (1)	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA, f = 500MHz	_	17.5	_	dB
	S21e  <sup>2</sup> (2)	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA, f = 1GHz	9.5	11.8	_	dB
Noise figure —	NF(1)	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA, f = 500MHz	_	0.91	_	dB
	NF(2)	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA, f = 1GHz	_	1.15	1.45	dB
3 <sup>rd</sup> order intermodulation distortion output intercept point	OIP3	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50mA, f = 500MHz, ⊿f=1MHz	32	35.9	_	dBmW

## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 5V, I <sub>E</sub> = 0	_	_	0.1	μΑ
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 30mA	200	_	400	_
Output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 5V, I <sub>E</sub> = 0, f = 1MHz	_	1.49	_	pF
Reverse transfer capacitance	C <sub>re</sub>	V <sub>CB</sub> = 5V, I <sub>E</sub> = 0, f = 1MHz (Note3)	_	0.94	1.25	pF

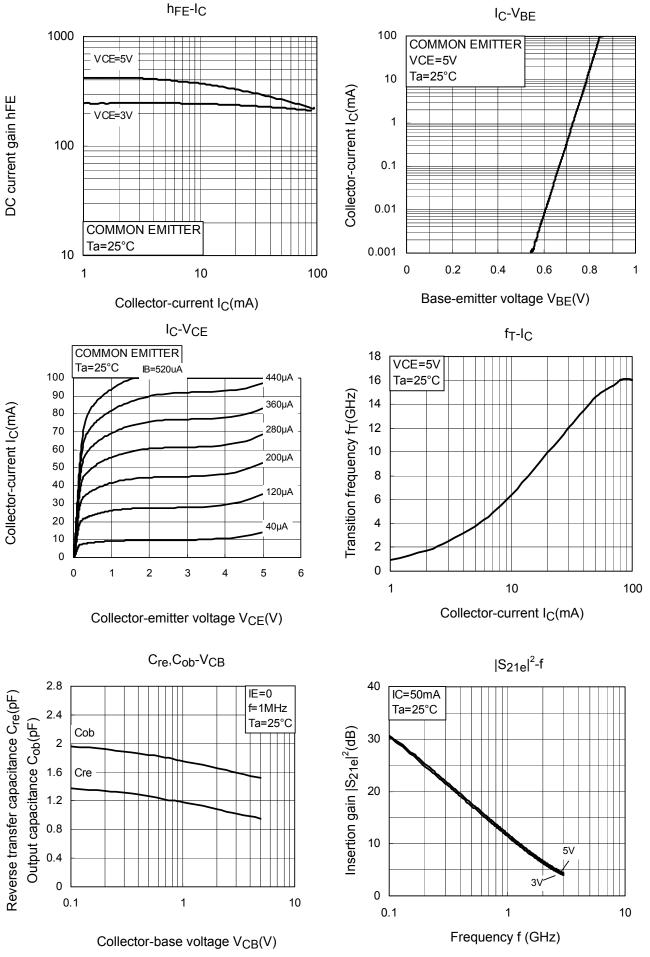
Note 3:C<sub>re</sub> is measured using a 3-terminal method with capacitance bridge

#### Caution:

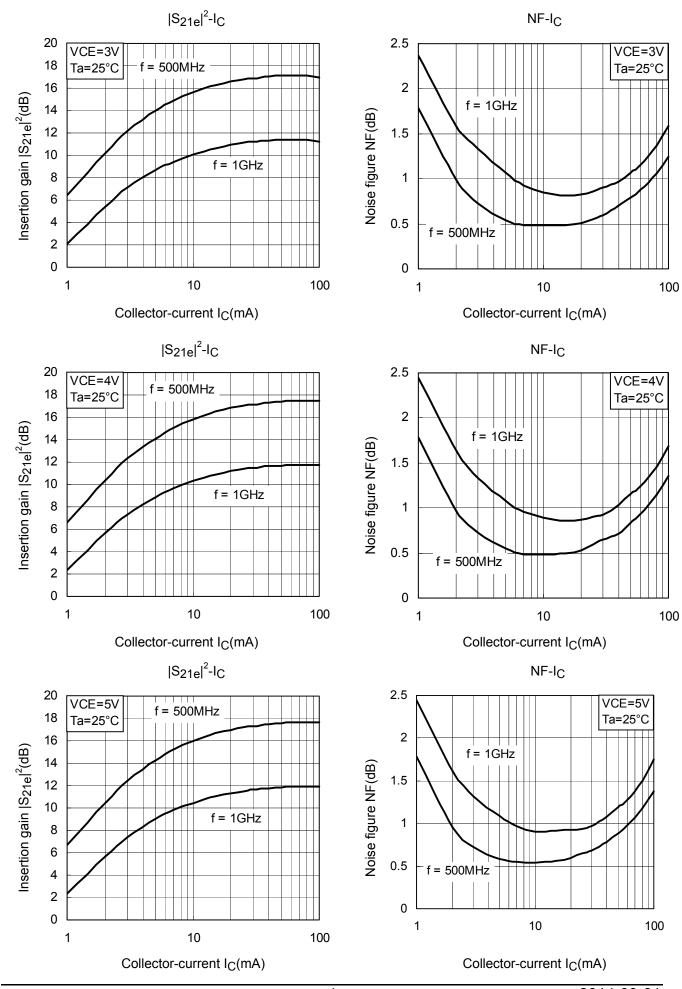
This device is sensitive to electrostatic discharge due to the high frequency transistor process of  $f_T$ =60GHz class is used for this product.

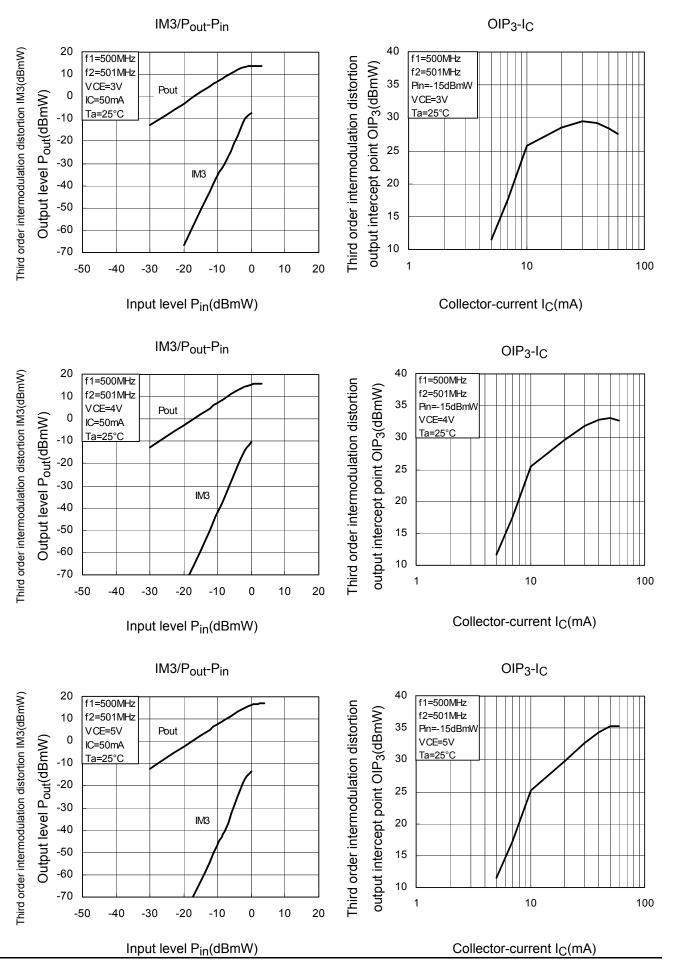
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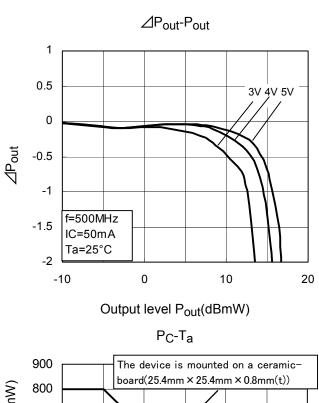
Please make enough tool and equipment earthed when you handle.

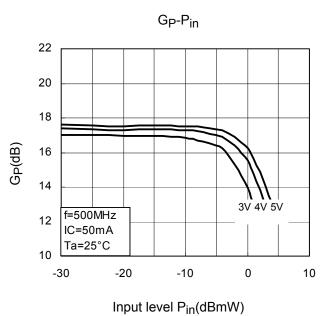


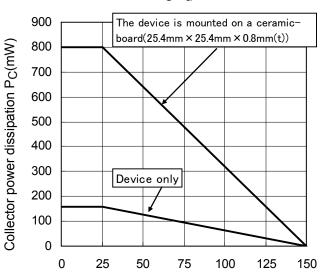
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Ambient temperature T<sub>a</sub>(°C)

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